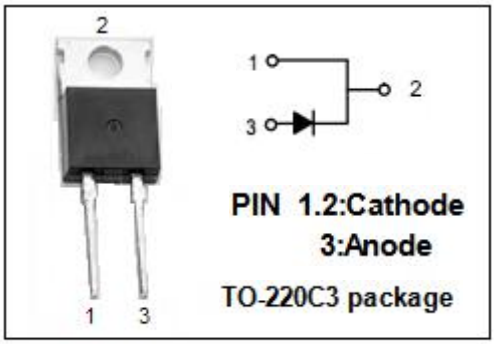
Schottky Barrier Rectifier

MS1004

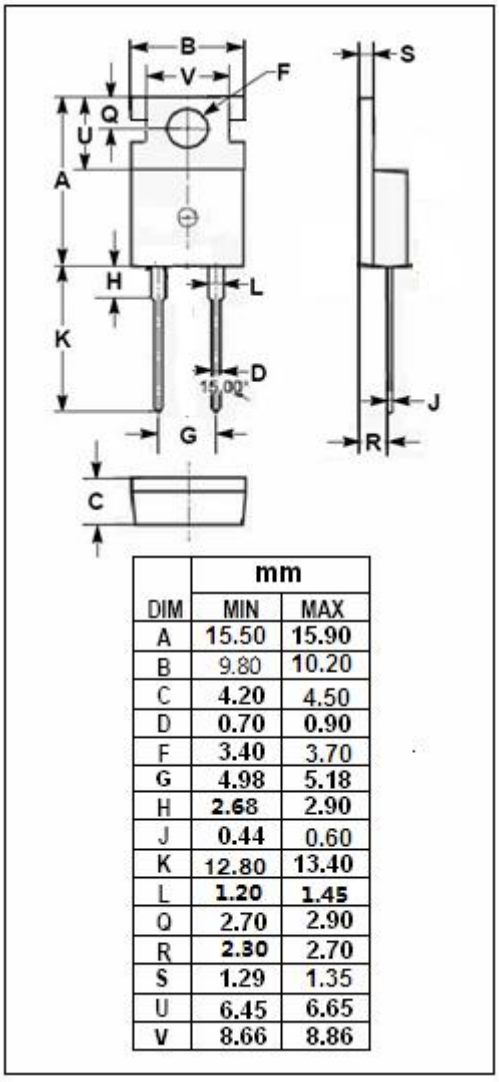


FEATURES

- Guard -Ring for Stress Protection
- Low Forward Voltage
- High Operating Junction Temperature
- Low Power Loss/High Efficiency
- High surge capability
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

MECHANICAL CHARACTERISTICS

- Case: Epoxy, Molded



DIM	mm MIN	mm MAX
A	15.50	15.90
B	9.80	10.20
C	4.20	4.50
D	0.70	0.90
F	3.40	3.70
G	4.98	5.18
H	2.68	2.90
J	0.44	0.60
K	12.80	13.40
L	1.20	1.45
Q	2.70	2.90
R	2.30	2.70
S	1.29	1.35
U	6.45	6.65
V	8.66	8.86

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V_{RRM} V_{RWM} V_R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	40	V
$I_{F(AV)}$	Average Rectified Forward Current) T_C= 125℃	10	A
I_{FSM}	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	225	A
T_J	Junction Temperature	-55~175	℃
T_{stg}	Storage Temperature Range	-55~175	℃
dv/dt	Voltage Rate of Change (Rated V_R)	10,000	V/μs

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j\text{-}c}$	Thermal Resistance,Junction to Case	2.5	℃/W

ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤2%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
V_F	Maximum Instantaneous Forward Voltage	I_F= 10A ; T_C= 25℃ I_F= 10A ; T_C= 175℃	0.65 0.48	V
I_R	Maximum Instantaneous Reverse Current	Rated DC Voltage, T_C= 25℃ Rated DC Voltage, T_C= 125℃	0.25 10	mA